



# Integrated Low Profile Transceiver Module for Low Power Applications 9. 6 kbit/s to 1.152 Mbit/s Data Transmission Rate



#### **Description**

The miniaturized TFBS5600<sup>1)</sup> and TFBS5607<sup>1)</sup> are ideal transceivers for applications in telecommunications like mobile phones, pagers, and PDAs of all kinds. The devices are both designed for optimum performance and minimum package size.

These devices cover the latest IrDA<sup>®</sup> physical layer specification for SIR and MIR 1.152 Mbit/s IrDA<sup>®</sup> mode.

Both transceivers are in a very low profile package, allowing to replace and upgrade a variety of common SIR devices to MIR functionality with the additional feature of variable logic voltage swing. The TFBS5607 is using the Vishay Telefunken, IBM® and Infineon® order of the pinning, the TFBS5600 is equivalent to the HSDL – 3202 (SIR device) pinning.

#### The new features

The devices are modifications of the TFDU5106/ TFDU5107 devices. An additional new feature as in TFDU5106/ TFDU5107 is the adjustable logic voltage  $V_{ddlogic}$  swing. It sets the input and output logic levels and can be applied externally with levels between 1.5 V and 5.5 V.

The device covers the supply voltage from 5.5 V down to 2.4 V and with its low current consumption of less than 250  $\mu$ A it is optimum suited for battery powered applications. Double eye safety protection by pulse duration and current limitation is integrated.

Both devices are designed to cover an extended low power range close to one meter. A custom modification current control for MIR low power standard with lower intensity setting is available on request.

#### **Features**

- Packages:
  - -TFBS5607 Vishay Legacy Pinning Order -TFBS5600 Pinning like HSDL-3201 with added functionality
- Compatible to IrDA Low Power Standard (MIR and SIR with Lowest Current Consumption)
- Wide Supply Voltage Range (2.4 V to 5.5 V)
- Operational down to 2.0 V
- Logic Input and Output Voltage 1.5 V to 5.5 V

- Tri State Receiver Output with weak pull-up efficient in shut down mode
- Lowest Power Consumption, typically 500 μA in Receive Mode,
   1 μA in Shutdown Mode
- Only typical 60 mA Average Current Consumption in 1.152 Mbit/s Transmit Mode
- Fewest External Components
- Vishay's well known High EMI Immunity
- Eye Safety Protection Integrated

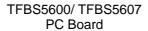
### **Applications**

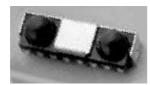
- Mobile Phones, Pagers, Hand-held Battery Operated Equipment
- Computers (WinCE, PalmPC, PDAs)
- Digital Still and Video Cameras
- Extended IR Adapters
- Medical and Industrial Data Collection

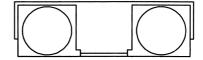
1) Customized version with different current control setting for IrDA Low Power standard can be selected, too.











## **Ordering Information**

| Part Number  | Qty / Reel | Description |
|--------------|------------|-------------|
| TFBS5600-TR3 | 2500 pcs   |             |
| TFBS5607-TR3 | 2500 pcs   |             |

## **Functional Block Diagram**

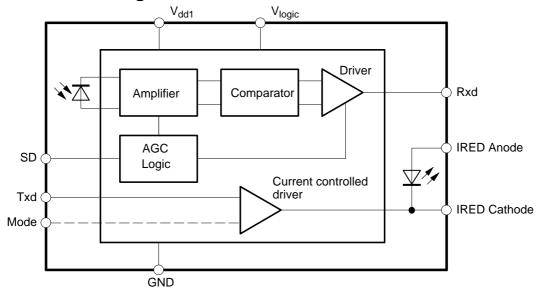


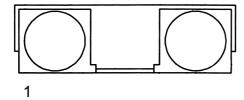
Figure 1. Functional Block Diagram (mode input is for internal current selection of customized version for low power or full IrDA range)



## **Pin Description**

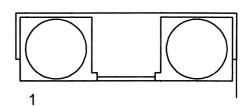
| Pin      | Pin      | Function           | Description   |   | Active |
|----------|----------|--------------------|---|---|--------|
| TFBS5600 | TFBS5607 |                    |   |   |        |
| 8        | 1        | IRED Anode         | IRED Anode to be externally connected to V <sub>CC</sub> through a current control resistor. This pin is allowed to be supplied from an uncontrolled power supply separated from the controlled V <sub>CC</sub> supply.  Described in US patent 08995536  |   |        |
|          | 2        | IRED Cathode       | IRED Cathode, internally connected to driver transistor   |   |        |
| 4        |          | AGND               | Analog Ground, to be externally connected to Ground   |   |        |
| 7        | 3        | Txd                | Transmit Data Input   | I | HIGH   |
| 6        | 4        | Rxd                | Received Data Output, push–pull CMOS driver output capable of driving a standard CMOS or TTL load. No external pull–up or pull–down resistor is required. Pin is connected to $V_{logic}$ with a weak pull-up (500 k $\Omega$ ) when device is in shutdown mode. Rxd output is quiet during transmission. | 0 | LOW    |
| 5        | 5        | SD                 | Shutdown, will switch the device into shutdown after a delay of 1 ms  | I | HIGH   |
| 3        | 6        | Vdd                | Supply Voltage  |   |        |
| 2        | 7        | V <sub>logic</sub> | Defines the input and output logic swing voltage  |   |        |
| 1        | 8        | GND                | Ground  |   |        |

#### TFBS5600 Second source pinning



Pin order: IREDA IRED C Txd Rxd SD Vdd Vlogic GND

#### TFBS5607 Vishay legacy pinning



Pin order: GND Vlogic Vdd AGND SD Rxd Txd IREDA

Figure 2. Pinning

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#### **Absolute Maximum Ratings**

Reference Point Ground, Pin 8, unless otherwise noted

| Parameters   | Test Conditions   | Symbol                 | Min. | Тур. | Max.                          | Unit  |
|--|---|------------------------|------|------|-------------------------------|-------|
| Supply Voltage Range                                       | 0 V < V <sub>dd2</sub> < 6 V  | V <sub>dd1</sub>       | -0.5 |      | 6                             | V     |
|  | 0 V < V <sub>dd1</sub> < 6 V  | $V_{dd2}$              | -0.5 |      | 6                             | V     |
|  | 0 V < V <sub>dd1</sub> < 6 V<br>0 V < V <sub>dd2</sub> < 6 V            | $V_{logic}$            | -0.5 |      | 6                             | V     |
| Input Current  | all pins<br>(IRED Anode excluded)                                       |                        |      |      | 10                            | mA    |
| Output Sink Current, Rxd                                   | Rxd   |                        |      |      | 25                            | mA    |
| Rep. Pulsed IRED Current                                   | IRED Anode,<br>t <sub>on</sub> < 20%, < 20 μs                           | I <sub>IRED</sub> (RP) |      |      | 500                           | mA    |
| Average IRED Current                                       |   | I <sub>IRED</sub> (DC) |      |      | 125                           | mA    |
| Power Dissipation  |   | P <sub>tot</sub>       |      |      | 450                           | mW    |
| Junction Temperature                                       |   | TJ                     |      |      | 125                           | °C    |
| Ambient Temperature Range (Operating)                      |   | T <sub>amb</sub>       | -25  |      | 85                            | °C    |
| Storage Temperature Range                                  |   | T <sub>stg</sub>       | -25  |      | 85                            | °C    |
| Soldering Temperature                                      | t = 20 s @215°C   |                        |      | 215  | 240                           | °C    |
| Transmitter Data and Shutdown Input Voltage                | 2.4 V < V <sub>dd1</sub> < 5.5 V  | $V_{Txd}$ , $V_{SD}$   | -0.5 |      | 6                             | V     |
| Receiver Data Output Voltage                               |   | $V_{Rxd}$              | -0.5 |      | V <sub>logic</sub> +0.5       | V     |
| Virtual source size  | Method:<br>(1–1/e) encircled energy                                     | d                      | 2.5  | 2.8  |                               | mm    |
| Max. Intensity for Class 1 operation of IEC 825 or EN60825 | EN60825, 1.1.1997<br>Worst case IrDA pulse<br>pattern, lab. conditions. |                        |      |      | save in all operation modes*) | mW/sr |

<sup>\*)</sup> The device is protected against Txd short by an internal shut-off when the pulse duration is exceeding maximum IrDA specification value of pulse duration. In addition the max. current is limited. When using an additional current control resistor the device is fully protected equivalent to IEC 60825–1, amendment 2, edition 01.01.2001





## **Optoelectronic Characteristics**

 $T_{amb}$  = 25°C,  $V_{dd1}$  = 2.4 V to 5.5 V unless otherwise noted. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

| Parameters  | Test Conditions   | Symbol            | Min. | Тур. | Max. | Unit   |
|---|---|-------------------|------|------|------|--------|
| Transceiver                                       |   |                   |      |      |      |        |
| Supported Data Rates<br>Rxd pulse duration 400 ns | Base band<br>MIR  |                   | 9.6  |      | 1152 | kbit/s |
| Supply Current receive mode                       | $V_{dd1} = 2.4 \text{ V to } 5.5 \text{ V}$                                 | Is                |      |      | 900  | μΑ     |
| Supply Current shutdown mode                      | $V_{dd1} = 2.4 \text{ V to } 5.5 \text{ V}$                                 | I <sub>SSD</sub>  |      | 0.1  | 1    | μΑ     |
| Average Supply Current during transmission        | I <sub>IREDpeak</sub> = 450 mA,<br>no external resistor,<br>IrDA full range | I <sub>S</sub>    |      | 60   | 120  | mA     |
| Shutdown /<br>Mode clock pulse duration           |   | t <sub>prog</sub> | 0.2  |      | 20   | μs     |
| Shutdown delay "Receive off"                      |   | t <sub>prog</sub> | 1    |      | 1.5  | ms     |
| Shutdown delay "Receive on"                       |   | t <sub>prog</sub> | 40   |      | 100  | μs     |
| Transceiver "Power on"<br>Settling Time           | Time from switching on V <sub>dd1</sub> to established specified operation  |                   |      | 50   |      | μs     |

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#### **Optoelectronic Characteristics**

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| Parameters   | Test Conditions  | Symbol                 | Min.                  | Тур.  | Max. | Unit              |
|--|--|------------------------|-----------------------|-------|------|-------------------|
| Receiver   |  | ,                      |                       | 71    |      |                   |
| Minimum Detection<br>Threshold Irradiance<br>9.6 kbit/s to 1.152 Mbit/s *) | $ \alpha  \le \pm 15^{\circ}$<br>V <sub>dd1</sub> = 2.4 V to 5.5 V             | E <sub>e, min</sub>    |                       | 40    | 80   | mW/m <sup>2</sup> |
| Maximum Detection Threshold Irradiance                                     | $\begin{vmatrix}  \alpha  \le \pm 90^{\circ} \\ V_{dd1} = 5 \ V \end{vmatrix}$ | E <sub>e, max</sub>    |                       | 5000  |      | W/m <sup>2</sup>  |
|  | $ \alpha  \le \pm 90^{\circ}$ $V_{dd1} = 3 \text{ V}$                          | E <sub>e, max</sub>    | 8000                  | 15000 |      | W/m <sup>2</sup>  |
| Logic Low Receiver Input Irradiance  |  | E <sub>e,max,low</sub> | 4                     |       |      | mW/m <sup>2</sup> |
| Output Voltage Rxd   | active   | V <sub>OL</sub>        |                       | 0.5   | 0.8  | V                 |
|  | $C = 15 \text{ pF}, R = 2.2 \text{ k}\Omega$                                   |                        |                       |       |      |                   |
|  | non active   | V <sub>OH</sub>        | V <sub>dd1</sub> –0.5 |       |      | V                 |
|  | $C = 15 \text{ pF}, R = 2.2 \text{ k}\Omega$                                   |                        |                       |       |      |                   |
| Output Current Rxd<br>V <sub>OL</sub> < 0.8 V                              |  |                        |                       |       | 4    | mA                |
| Rise Time @Load:<br>C = 15 pF, R = 2.2 k $\Omega$                          | 1.5 V ≤ V <sub>logic</sub> < 1.8 V   | t <sub>r</sub>         |                       | 30    |      | ns                |
| Fall Time @Load:<br>C = 15 pF, R = 2.2 k $\Omega$                          | 1.5 V ≤ V <sub>logic</sub> < 1.8 V   | t <sub>f</sub>         |                       | 30    |      | ns                |
| Rise Time @Load:<br>C = 15 pF, R = 2.2 k $\Omega$                          | 1.8 V ≤ V <sub>logic</sub> < 5.5 V   | t <sub>r</sub>         |                       | 25    | 40   | ns                |
| Fall Time @Load:<br>C = 15 pF, R = 2.2 k $\Omega$                          | 1.8 V ≤ V <sub>logic</sub> < 5.5 V   | t <sub>f</sub>         |                       | 25    | 40   | ns                |
| Rxd Signal Electrical Output<br>Pulse Width                                | 1.5 V ≤ V <sub>logic</sub> < 5.5 V   | t <sub>p</sub>         | 250                   | 400   | 550  | ns                |
| Latency  | MIR mode   | tL                     |                       | 50    | 200  | μs                |

<sup>\*)</sup> Rxd output pulse duration nominal 400 ns for all speeds.





## **Optoelectronic Characteristics**

 $T_{amb}$  = 25 °C,  $V_{dd1}$  = 2.4 V to 5.5 V unless otherwise noted. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

| Parameters  | Test Conditions  | Symbol                          | Min.                        | Тур.                   | Max.                        | Unit  |
|---|--|---------------------------------|-----------------------------|------------------------|-----------------------------|-------|
| Transmitter   |  | •                               |                             |                        |                             |       |
| Logic CMOS High/Low Decision Threshold                        |  | V <sub>IL</sub> (Txd)           |                             | 1/2xV <sub>logic</sub> |                             | V     |
| Logic Low Transmitter Input Voltage                           |  | V <sub>IL</sub> (Txd)           | 0                           |                        | 0.2*)<br>V <sub>logic</sub> | V     |
| Logic High Transmitter Input Voltage                          | 1.5 V < V <sub>logic</sub> < 5.5 V                         | V <sub>IH</sub> (Txd)           | 0.8*)<br>V <sub>logic</sub> |                        | V <sub>logic</sub><br>+0.5  | V     |
| Output Radiant Intensity,  α  ≤ 15° MIR level full IrDA range | $V_{dd2} = 2.7 \text{ V}$<br>(I <sub>F</sub> = 450 mA)     | l <sub>e</sub>                  | 40                          | 90                     |                             | mW/sr |
| Controlled IRED drive peak current*)                          | $V_{dd2} = 2.7 \text{ V to} $<br>$V_{dd2} = 5.5 \text{ V}$ |                                 |                             | 450                    |                             | mA    |
| Maximum Output Pulse width (eye safety protection)            | P <sub>WI</sub> > 23 μs                                    | P <sub>WOmin</sub>              | 23                          |                        | 80                          | μs    |
| Optical Pulse width   | P <sub>WI</sub> > 1.6 μs                                   | P <sub>WO</sub>                 | 1.45                        |                        | 1.75                        | μs    |
|   | P <sub>WI</sub> > 217 ns                                   | P <sub>WO</sub>                 | 210                         |                        | 226                         | ns    |
| Optical Rise/Falltime   |  | t <sub>r</sub> , t <sub>f</sub> |                             |                        | 40                          | ns    |
| Peak Wavelength of Emission                                   |  | λρ                              | 880                         |                        | 900                         | nm    |
| Spectral Optical Radiation<br>Bandwidth                       |  | $\Delta_{\lambda}$              |                             | 45                     |                             | nm    |
| Output Radiant Intensity                                      | Txd logic low level  | I <sub>e</sub>                  |                             |                        | 0.04                        | μW/sr |
| Overshoot, Optical  |  |                                 |                             |                        | 25                          | %     |
| Rising Edge Peak to Peak Jitter                               |  | t <sub>i</sub>                  |                             |                        | 0.2                         | μs    |

<sup>\*)</sup> The current through the IRED can be defined also by an external resistor, internal current limitation to 450 mA peak, nominal. For operating above 4 V an external resistor is to be used for internal power dissipation reduction



#### **Recommended SMD Pad Layout**

The leads of the device should be soldered in the center position of the pads.

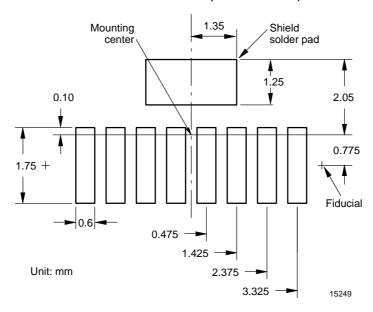


Figure 3. TFBS5600/TFBS5607

#### **Recommended Solder Profile**

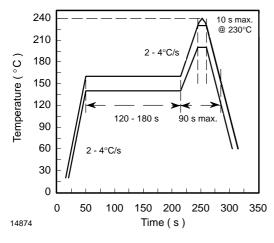


Figure 4. Recommended Solder Profile

#### **Current Derating Diagram**

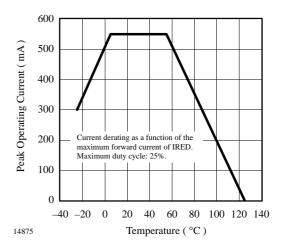


Figure 5. Current Derating Diagram

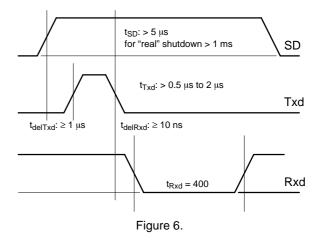




#### Identification

The identification of the device can be recalled by setting the SD active followed by activating Txd for a short period. With the low going edge of Txd a single pulse is generated at Rxd.

The SD is indendet to activate the shutdown function after a delay of 1 ms. Therefore the full sequence should be run with that 1 ms time limitation, see drawing.



## V<sub>logic</sub> Setting

The logic voltage swing is set by applying an external voltage to the  $V_{\text{logic}}$  pin.

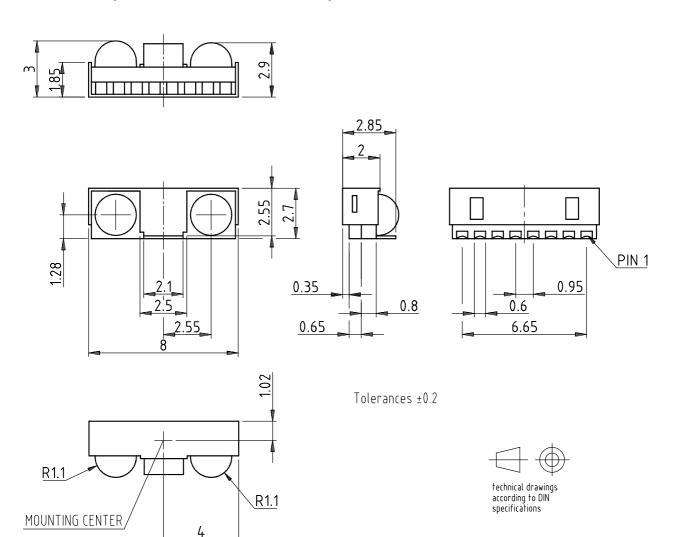
Table 1. Truth table

|             | Inputs       |   | Outputs  |  |  |
|-------------|--------------|---|--|--|--|
| SD          | Txd          | Optical input<br>Irradiance<br>mW/ m <sup>2</sup> | Rxd  | LED drive current resulting intensity I <sub>e</sub> in mW/ sr |  |
| high < 1 ms | pulse        | х   | low going Txd triggers<br>monostable to edit a<br>400 ns low pulse | 0  |  |
| high > 1 ms | Х            | х   | floating (500 k $\Omega$ to V <sub>dd</sub> )                      | 0  |  |
| low         | high         | х   | high   | > 10   |  |
| low         | high > 80 μs | х   | high   | 0  |  |
| low         | low          | < 4   | high   | 0  |  |
| low         | low          | ≥ 40  | low, edge triggered pulse of 400 ns durating                       | 0  |  |

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## **TFBS5600 (Mechanical Dimensions)**



Drawing-No.: 6.550-5227.01-4

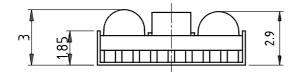
Issue: 1; 29.09.00

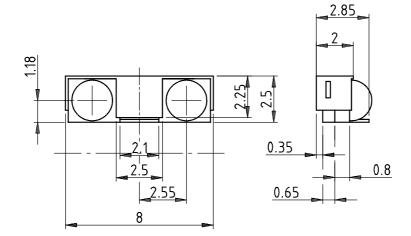
Dimensions in mm

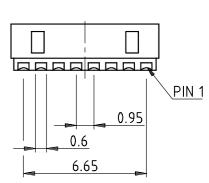
16504

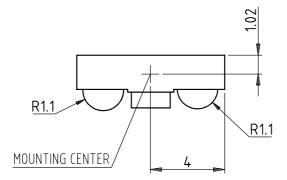


## **TFBS5607 (Mechanical Dimensions)**









Tolerances ±0.2



according to DIN specifications

Drawing-No.: 6.550-5226.01-4

Issue: 1; 29.09.00

Dimensions in mm

16503

## **Appendix**

#### **Application Hints**

## Recommended Circuit Diagram TFBS5600, TFBS5607

The TFBS5600 and TFBS5607 do not need any external components when operated at a "clean" power supply. In a more noisy ambient it is recommended to add a combination of a resistor and capacitor (R1, C1, C2) for noise suppression as shown in the figure below. A combination of a electrolytic for the low frequency range and a ceramic capacitor for suppressing the high frequency disturbance will be most effective. The capacitor C3 is only necessary when inductive wiring is used or the power supply cannot deliver the operating peak pulse current. However, a low impedance layout is the better and more cost efficient solution.

The inputs TXD and SD are high impedance CMOS inputs. Therefore, the lines from the I/O to those inputs should be carefully designed not to pick up ambient noise. If long lines are used, loads at the Txd input of the TFBS560x and at the Rxd input of the controller (!) are recommended. At the IRED Anode voltage supply line an additional capacitor might be necessary when inductive wiring is used. For adjusting the intensity depending on the application, a serial in the Vcc2 supply to the IRED Anode pin can be used.

For standard computer power supplies as first approach the recommended values from table 1 should be taken.

#### **Shut Down**

To shut down the TFBS5600 into a standby mode the SD pin has to be set active. After a delay of < 1 ms it will switch to the standby mode.

#### Latency

The receiver is in specified conditions after the defined latency. In a UART related application after that time (typically 50  $\mu s$ ) the receiver buffer of the UART must be cleared. Therefore, the transceiver has to wait at least the specified latency after receiving the last bit before starting the transmission to be sure that the corresponding receiver is in a defined state.

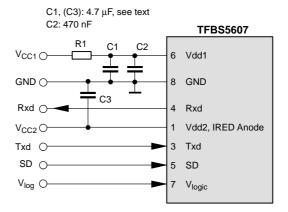


Figure 7. Recommended Application Circuit

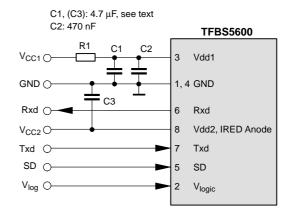


Figure 8. Recommended Application Circuit

Table 2. Recommended Application Circuit Components

| Component | Recommended Value | Vishay Part Number   |
|-----------|-------------------|----------------------|
| C1, C3    | 4.7 μF, 16 V      | 293D 475X9 016B 2T   |
| C2        | 0.47 μF, Ceramic  | VJ 1206 Y 104 J XXMT |
| R1        | 47 Ω, 0.125 W     | CRCW-1206-47R0-F-RT1 |

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## **Revision History:**

A1.0, 25/02/2000: Target, 1st edition

Derived from... 06/07 version

A0.9a, 19/04/2000: Target, tolerances for package height added, based on first mechanical package lots.

A1.0, 14/02/2001: Final revision

Document Number 82540 Rev. A1.0, 14-Feb-01 www.vishay.com 13 (14)

#### Vishay Telefunken



#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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